RT3NFFM

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

DESCRIPTION

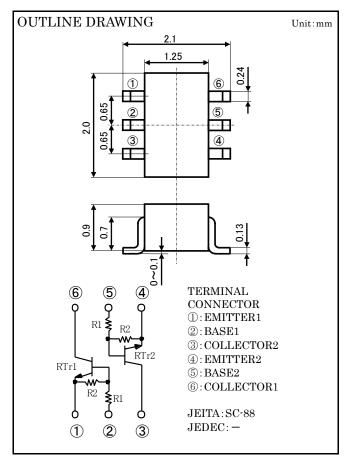
RT3NFFM is composite transistor built with two RT1N431 chips in SC-88 package.

FEATURE

Built-in bias resistor (R1=4.7k Ω , R2=4.7k Ω) Mini package for easy mounting

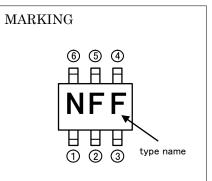
APPLICATION

Inverted circuit, Switching circuit, Interface circuit, Driver circuit



MAXIMUM RATING(Ta=25°C)(RTr1, RTr2 COMMON)

SYMBOL	PARAMETER	RATING	UNIT	
VCBO	Collector to Base voltage	50	V	
VEBO	Emitter to Base voltage	10	V	
VCEO	Collector to Emitter voltage	50	V	
$V_{\rm IN}$	Input voltage	30	V	
Ic	Collector current	100	mA	
ICM	Peak Collector current	200	mA	
Рт	Total dissipation	200	mW	
Tj	Junction temperature	+150	°C	
Tstg	Storage temperature	-55~+150	°C	



ELECTRICAL CHARACTERISTICS(Ta=25°C)(RTr1, RTr2 COMMON)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	UNIT
V(BR)CEO	Collector to Emitter breakdown voltage	$I_{C}=100 \mu$ A, $R_{BE}=\infty$	50	—	—	V
Ісво	Collector cut off current	V_{CB} =50V, I_E =0	1	_	0.1	μA
IEBO	Emitter cut off current	$V_{EB}=5V$, $I_C=0$	399	532	771	μA
hFE	DC forward current gain	V _{CE} =5V, I _C =10mA	20	—	—	_
VCE(sat)	Collector to Emitter saturation voltage	I _C =10mA, I _B =0.5mA	1	—	0.3	V
V _{I(ON)}	Input on voltage	V _{CE} =0.2V, I _C =5mA	-	1.4	2.3	V
V _{I(OFF)}	Input off voltage	$V_{CE}=5V$, $I_C=100 \mu A$	0.8	1.1	—	V
R_1	Input resistor	-	3.3	4.7	6.1	kΩ
R_2/R_1	Resistor ratio	-	0.8	1.0	1.2	_
f_{T}	Gain band width product	$V_{CE}=6V$, $I_{E}=-10mA$		200	_	MHz

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RT3NFFM

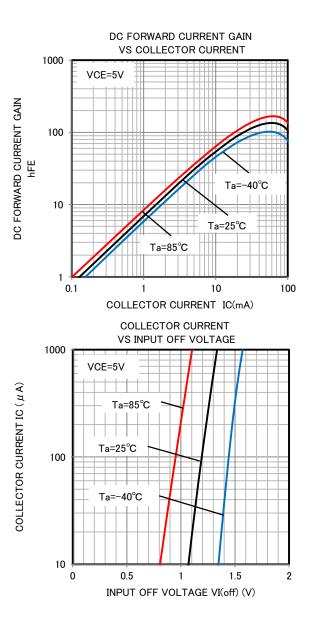
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300 (MM) TOTAL DISSIPATION PT 00 0 0 25 50 75 100 125 150 AMBIENT TEMPERATURE Ta (°C) INPUT ON VOLTAGE VS COLLECTOR CURRENT 10 VCE=0.2V 40°C Tа Ta=25°C INPUT ON VOLTAGE VI(on) (V) Ta=85°C 1 0.1 10 100 1 COLLECTOR CURRENT IC(mA) COLLECTOR TO EMITTER SATURATION VOLTAGE VS COLLECTOR CURRENT 1 IC/IB=20/1 COLLECTOR TO EMITTER SATURATION Ta=85℃ VOLTAGE VCE(sat) (V) Ta=25°C Ta=−40°C 0.1 0.01

10

COLLECTOR CURRENT IC(mA)

1



TYPICAL CHARACTERISTICS

TOTAL DISSIPATION

VS AMBIENT TEMPERATURE

(RTr1,RTr2 COMMON)

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100

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